NSN 5962-01-360-1551

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View Online at https://aerobasegroup.com/nsn/5962-01-360-1551

| view Offilite at https://defobasegroup.com/nsi//0302-01-300-1331 |
|--|
| Body Length: |
| Between 11.23 millimeters and 11.68 millimeters |
| Body Width: |
| Between 11.23 millimeters and 11.68 millimeters |
| Body Height: |
| Between 1.52 millimeters and 2.54 millimeters |
| Maximum Power Dissipation Rating: |
| 1.0 watts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| Features Provided: |
| Burn in and monolithic and programmed |
| Inclosure Material: |
| Ceramic |
| Inclosure Configuration: |
| Leadless flat pack |
| Output Logic Form: |
| Complementary-metal oxide-semiconductor logic |
| Input Circuit Pattern: |
| 14 input |
| Case Outline Source And Designator: |
| C-4 mil-m-38510 |
| Current Rating Per Characteristic: |
| 120.00 milliamperes reverse current, dc absolute |
| Terminal Surface Treatment: |
| Solder |
| Voltage Rating And Type Per Characteristic: |
| -0.5 volts power source and 7.0 volts power source |
| Time Rating Per Chacteristic: |
| 45.00 nanoseconds access |
| Memory Device Type: |
| Eprom |
| Test Data Document: |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). |
| Terminal Type And Quantity: |
| 28 leadless |
| Shelf Life: |
| N/a |
| Unit Of Measure: |

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Demilitarization:

No

Fiig:

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